

Silicon Neurons

NE-I Class

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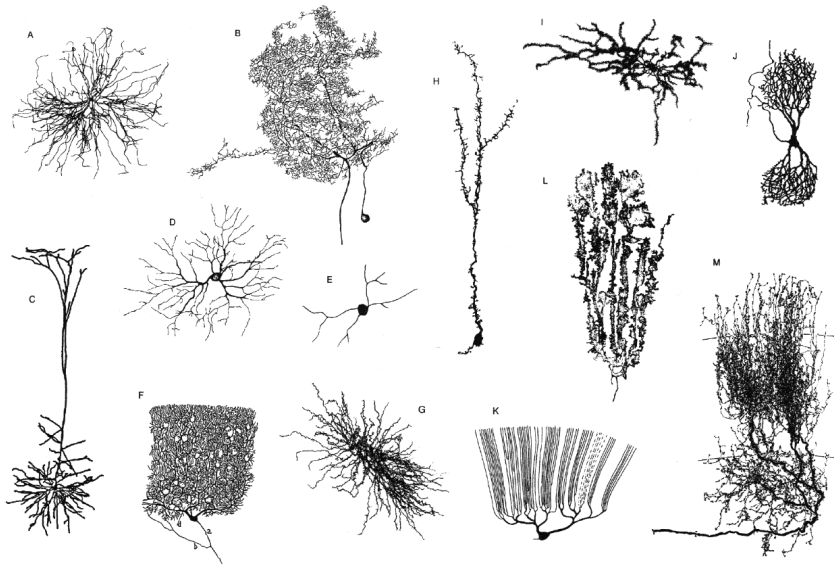
Neurons ... in a nutshell

A quick tutorial

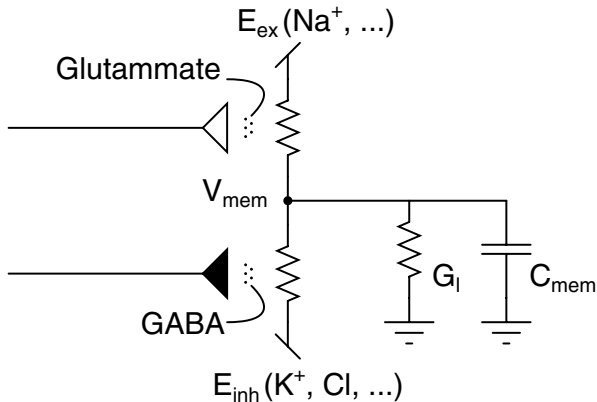
Complexity ↑

- *RealNeurons*
- Conductance based models
- Integrate and fire models
- Rate based models
 - ▶ Sigmoidal units
 - ▶ Linear threshold units

Neurons of the world

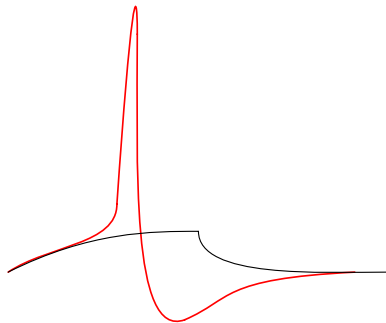
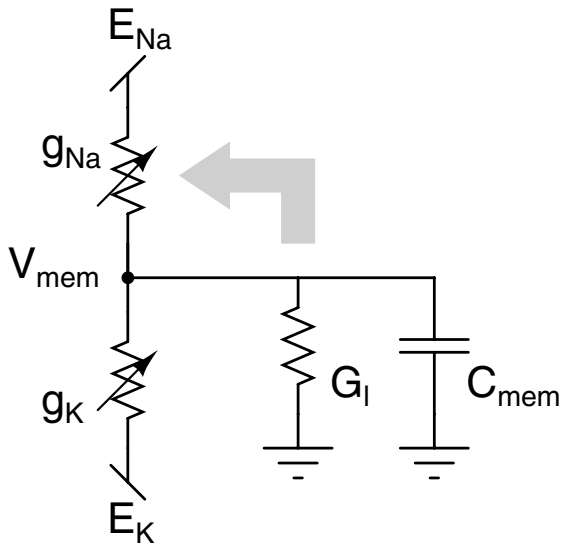


Equivalent Circuit

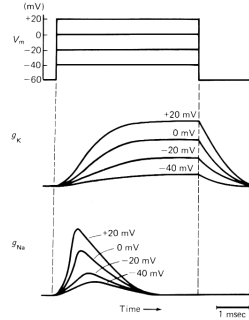
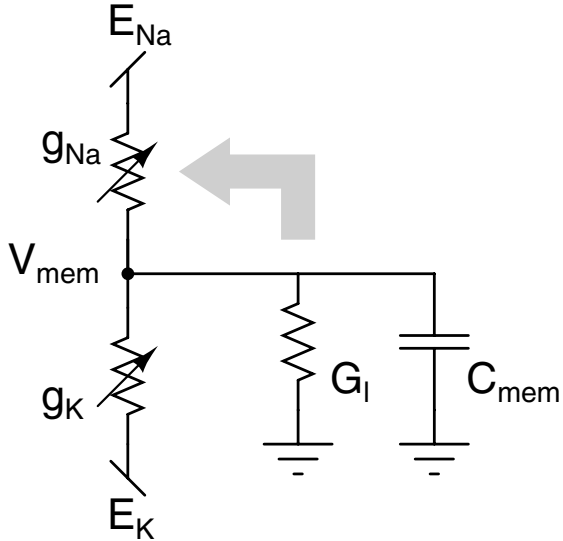


If excitatory input currents are relatively small, the neuron behaves exactly like a first order low-pass filter.

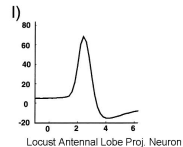
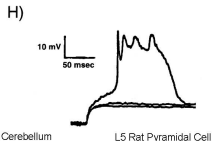
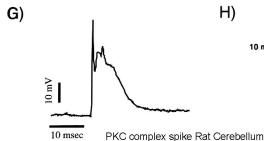
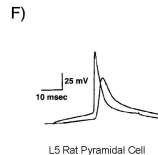
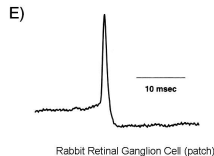
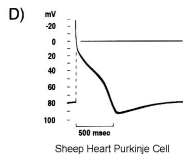
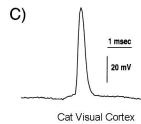
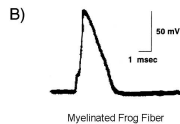
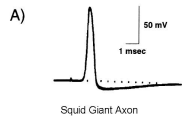
Spike generating mechanism



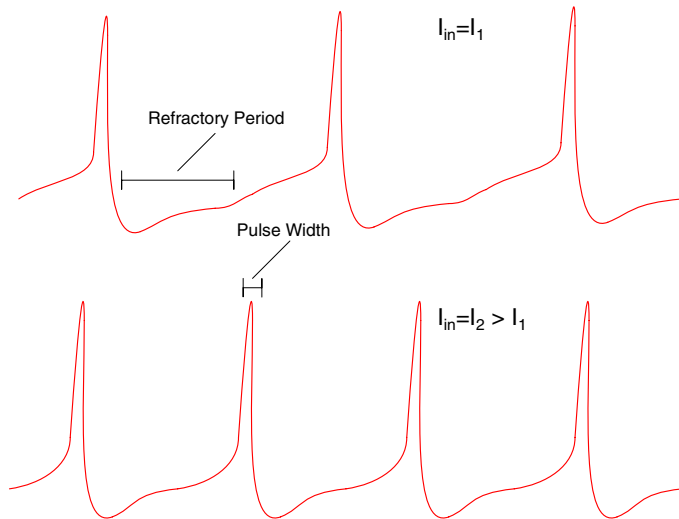
Spike generating mechanism



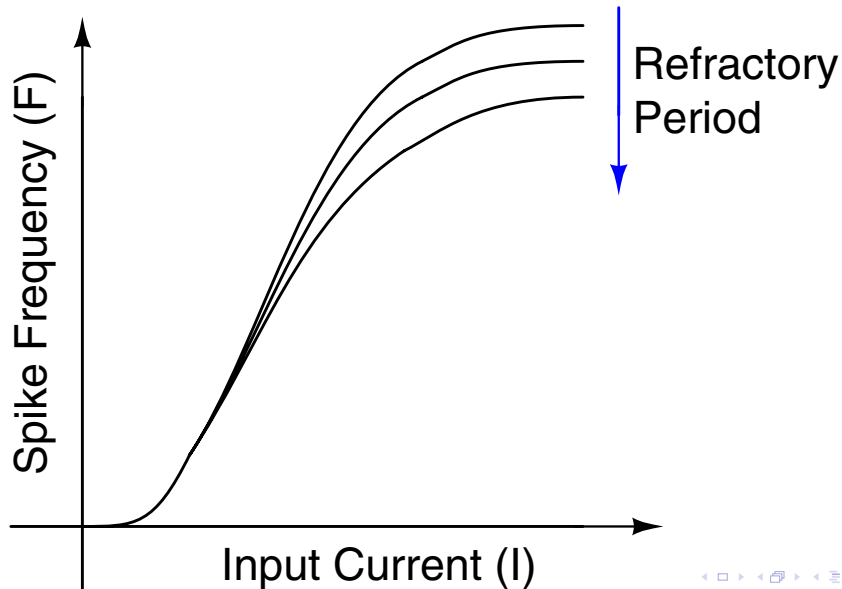
Action potentials of the world



Spike properties



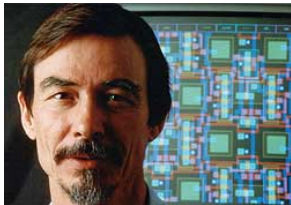
The F-I curve



Hardware implementations of spiking neurons

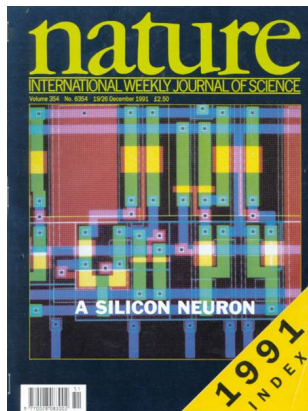
The first artificial neuron model was proposed in the **1943** by McCulloch and Pitts. Hardware implementations of this model date almost back to the same period.

Hardware implementations of *spiking* neurons are relatively new.



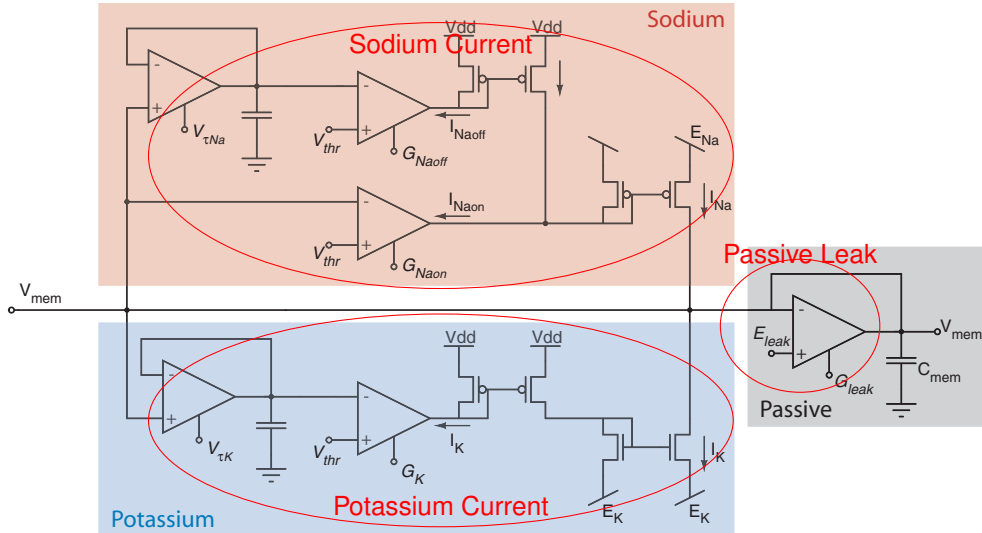
One of the most influential circuits that implements an *integrate and fire* (I&F) model of a neuron was the Axon-Hillock Circuit, proposed by Carver Mead in the late **1980s**.

Conductance-based models of spiking neurons



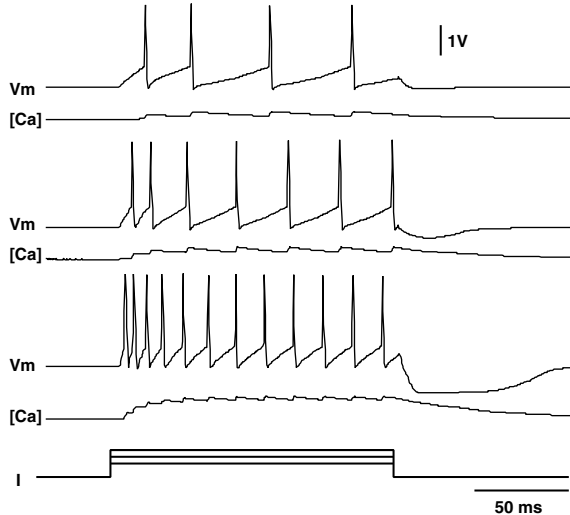
In **1991** Misha Mahowald and Rodney Douglas proposed a conductance-based silicon neuron and showed that it had properties remarkably similar to those of real cortical neurons.

Conductance based Si-Neurons



Conductance based Si-Neurons

Silicon neuron's measurements



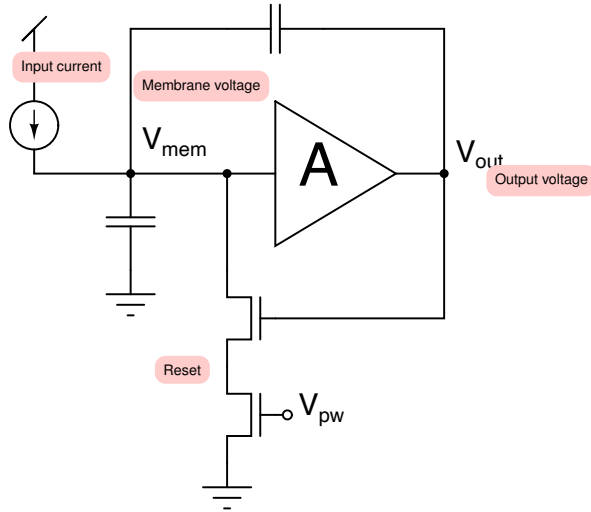
Neurons ... in a nutshell

A quick tutorial

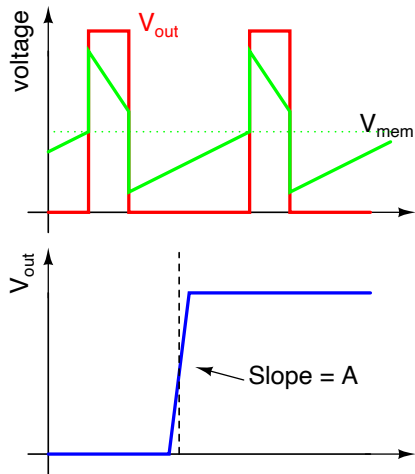
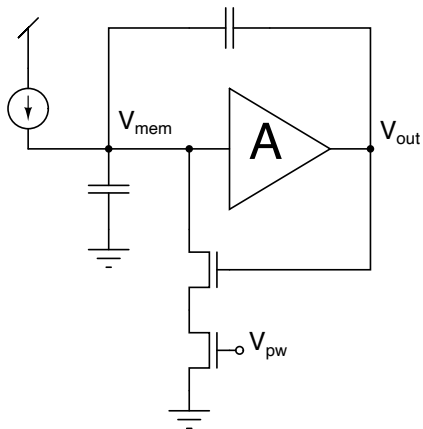
Complexity ↑

- Real Neurons
- Conductance based models
- **Integrate and fire models**
- Rate based models
 - ▶ Sigmoidal units
 - ▶ Linear threshold units

The Axon-Hillock Circuit



The Axon-Hillock Circuit



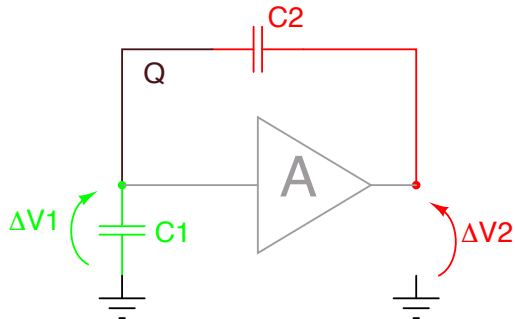
Capacitive Divider

Given the change ΔV_2 , what is ΔV_1 ?

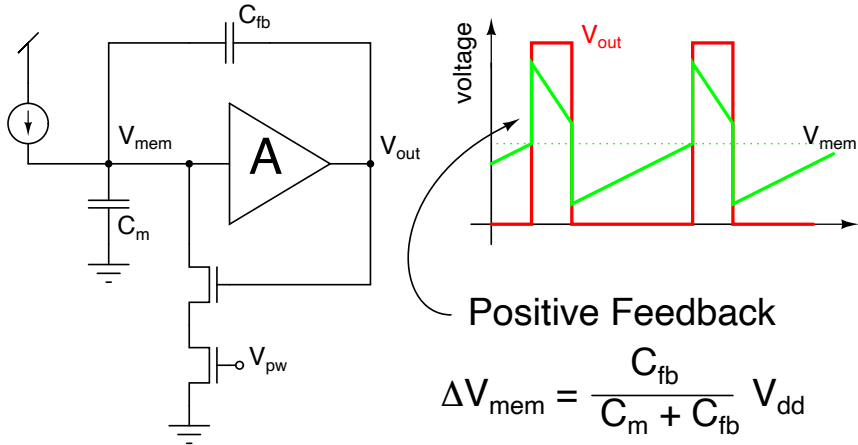
$$Q = C_1 V_1 + C_2 (V_1 - V_2) = \text{constant}$$

$$C_1 \Delta V_1 + C_2 (\Delta V_1 - \Delta V_2) = 0$$

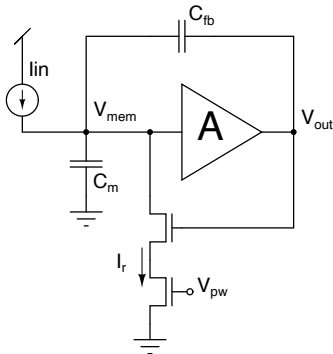
$$\Delta V_1 = \frac{C_2}{C_1 + C_2} \Delta V_2$$



Positive Feedback

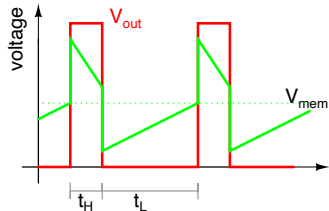


Axon-Hillock Circuit Dynamics



$$t_L = \frac{C_{fb} + C_m}{I_{in}} \Delta V_{mem} = \frac{C_{fb}}{I_{in}} V_{dd}$$

Frequency $\propto I_{in}$

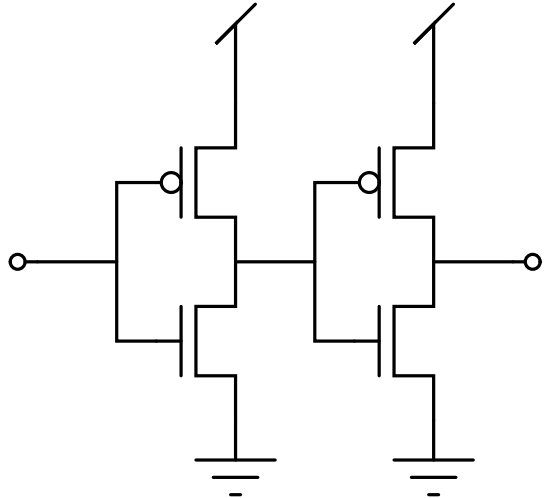
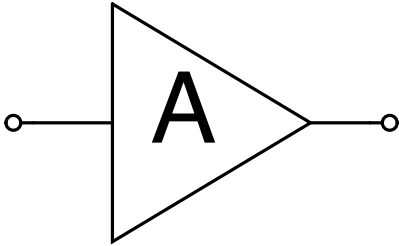


$$t_H = \frac{C_{fb} + C_m}{I_r - I_{in}} \Delta V_{mem} = \frac{C_{fb}}{I_r - I_{in}} V_{dd}$$

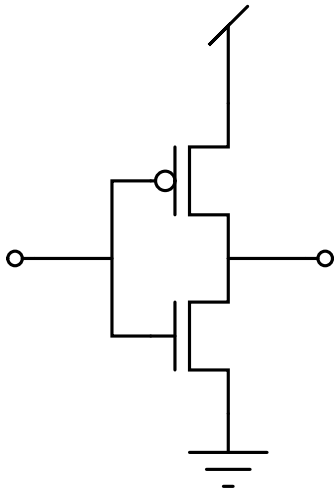
Pulse width $\propto 1/I_r$ for $I_r \gg I_{in}$

Gain

How to make voltage gain



Power Dissipation

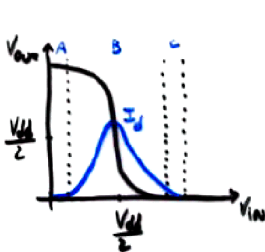


The Axon-Hillock circuit is very compact and allows for implementations of dense arrays of silicon neurons

BUT

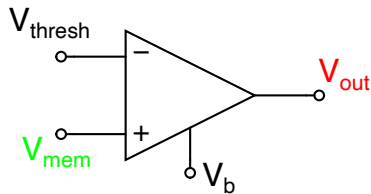
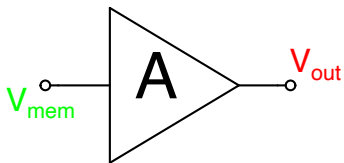
it has a major drawback: **power consumption**

During the time when an inverter switches, a large amount of current flows from V_{dd} to Gnd .

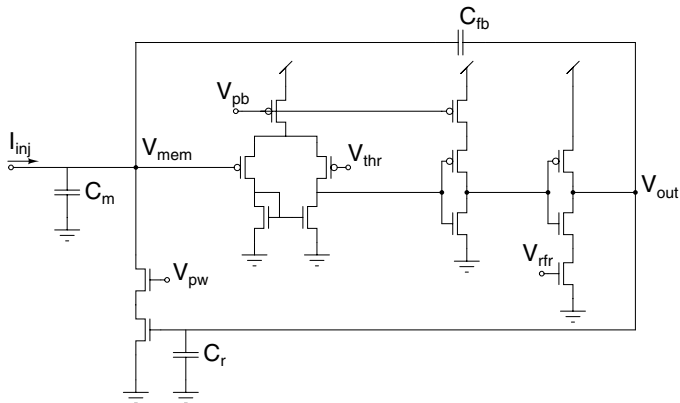


	$\frac{dH}{dt}$	$-\frac{dH}{dt}$
A:	ON	OFF
B:	ON	ON
C:	OFF	ON

Another way to make gain

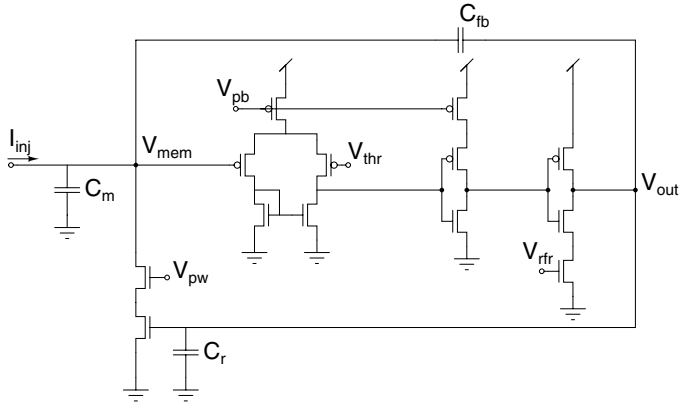


A more elaborate I&F circuit



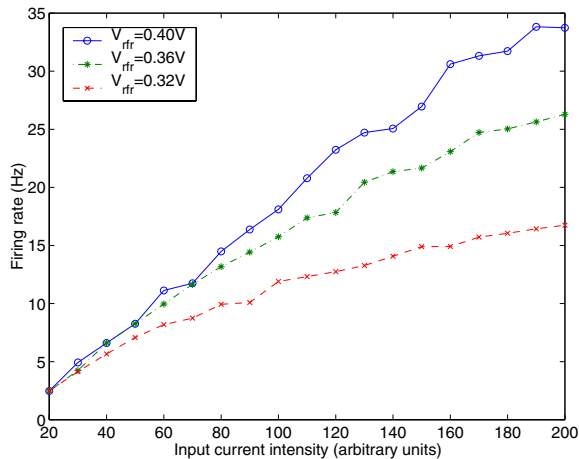
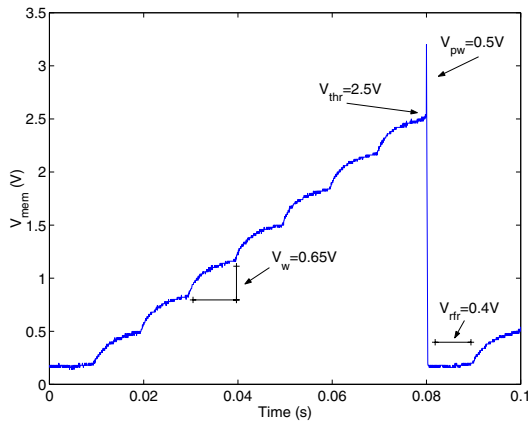
This circuit is low-power, has an explicit voltage threshold, and models the refractory period of real spikes.

A more elaborate I&F circuit



- V_{thr} sets the spiking voltage threshold
- V_{rfr} sets the refractory period length
- V_{pw} sets the pulse width

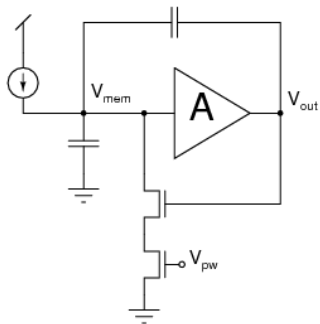
I&F circuit output



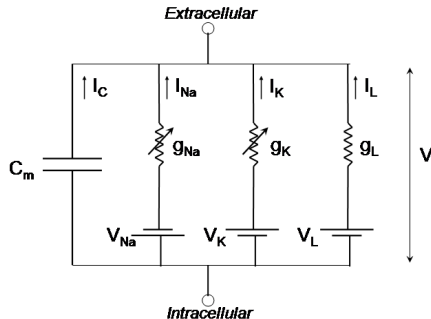
Conductance-based models

Integrate and Fire vs Hodgkin-Huxley

Traditionally there have been two main classes of neuron models:



Integrate and fire (I-C)



Conductance-based (R-C)

Conductance-based models

Integrate and Fire vs Hodgkin-Huxley

But recently proposed models bridge the gap between the two:

J Neurophysiol 92: 959–976, 2004;
10.1152/jn.00190.2004.

Generalized Integrate-and-Fire Models of Neuronal Activity Approximate Spike Trains of a Detailed Model to a High Degree of Accuracy

Renaud Jolivet,^{1,*} Timothy J. Lewis,^{2,*} and Wulfram Gerstner^{1,*}

J Neurophysiol 99: 656–666, 2008.

First published December 5, 2007; doi:10.1152/jn.01107.2007.

Dynamic I - V Curves Are Reliable Predictors of Naturalistic Pyramidal-Neuron Voltage Traces

Laurent Badel,¹ Sandrine Lefort,² Romain Brette,³ Carl C. H. Petersen,² Wulfram Gerstner,¹
and Magnus J. E. Richardson^{1,4}

Biol Cybern (2008) 99:361–370

DOI 10.1007/s00422-008-0259-4

ORIGINAL PAPER

Biological
Cybernetics

Extracting non-linear integrate-and-fire models from experimental data using dynamic I - V curves

Conductance-based models

Integrate and Fire vs Hodgkin-Huxley

But recently proposed models bridge the gap between the two:

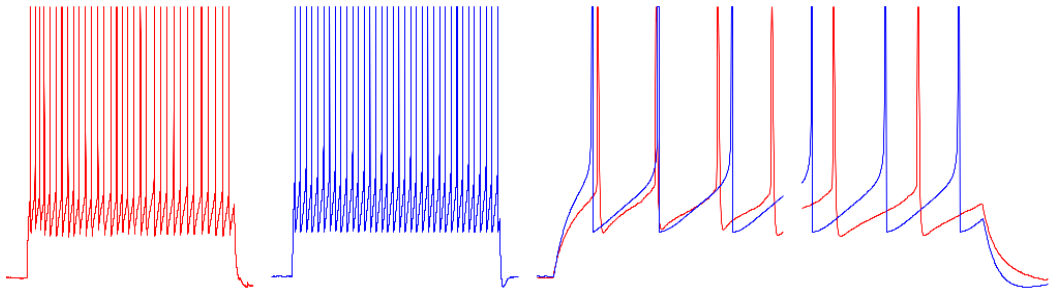
Generalized Integrate and Fire models can account for a very large set of behaviors captured by far more complicated Hodgkin-Huxley models.

$$\frac{d}{dt}u_{mem} = \frac{i_{in}}{C_{mem}} + F(u_{mem})$$

where $F(u_{mem})$ is a non-linear function of $u_{mem}(t)$.

Model neurons

The adaptive exponential I&F neuron model



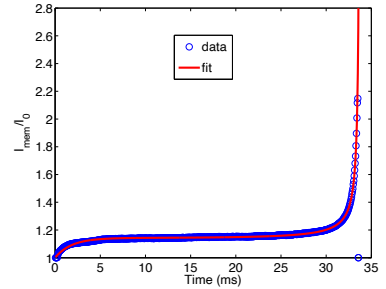
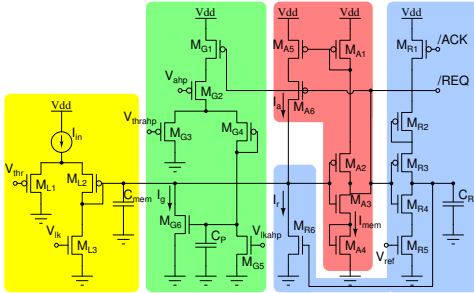
$$C \frac{d}{dt} V + g_L (V - E_L) = I - w + f(V)$$

$$\tau_w \frac{d}{dt} w + w = a(V - E_L)$$

[Brette and Gerstner, 2005]

Silicon neurons

The low power I&F neuron



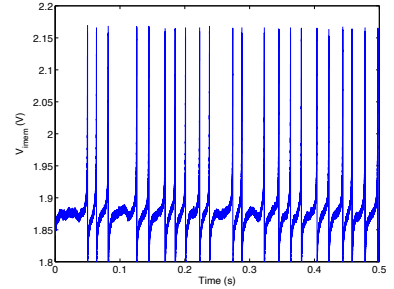
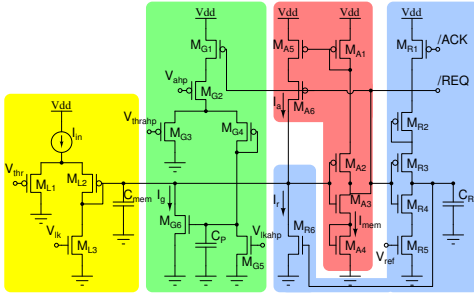
$$\tau \frac{d}{dt} I_{mem} + I_{mem} \approx \frac{I_{thr} I_{in}}{I_{\tau}} - I_g + f(I_{mem})$$

$$\tau_{ahp} \frac{d}{dt} I_g + I_g = \frac{I_{thr} I_{ahp}}{I_{\tau_{ahp}}}$$

[Indiveri et al., 2010] [Brette and Gerstner, 2005]

Silicon neurons

The low power I&F neuron



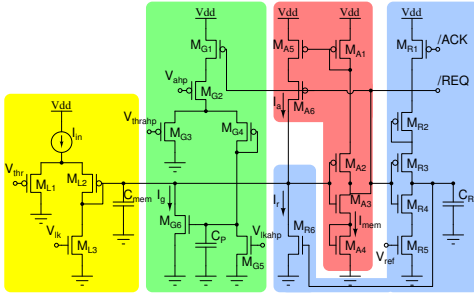
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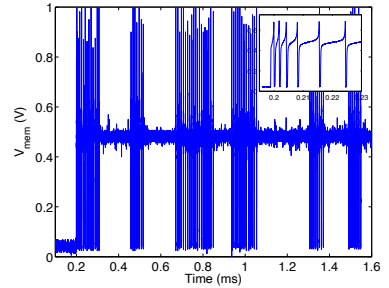
[Indiveri et al., 2010] [Brette and Gerstner, 2005]

Silicon neurons

The low power I&F neuron



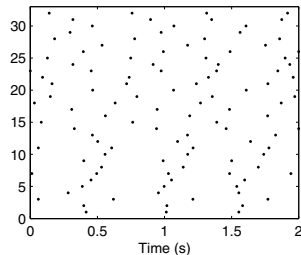
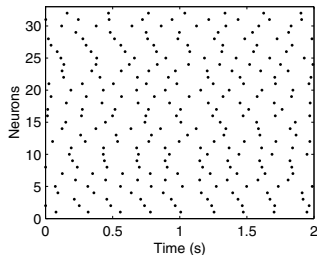
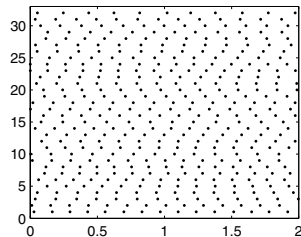
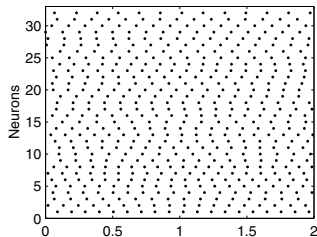
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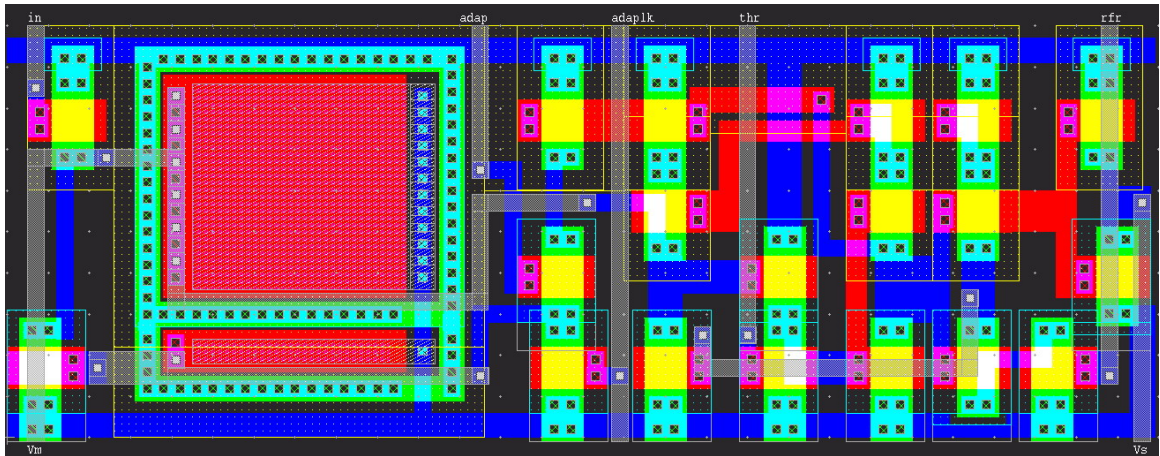
$$\tau_{ahp} \frac{d}{dt} I_g + I_g = \frac{I_{thr} I_{ahp}}{I_{\tau_{ahp}}}$$

[Indiveri et al., 2010] [Brette and Gerstner, 2005]

An ultra low-power array of I&F circuits



Silicon neuron layout



Applications

- Basic research
- Neuromorphic Sensors
- Multi-chip sensor-actuator systems
- Computation ?